

Circuit diagram

10 (N. C) 🔿

8(N.C) C

7 (N. C)

-0 1

o 3, 4

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\*Do not connect anything to NC pin.

## Application

- · Motor drive
- · Converter
- · Photovoltaics, wind power generation.

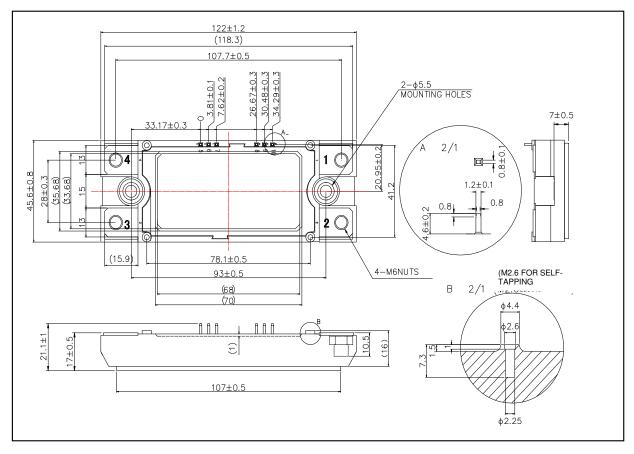
#### Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

### Construction

This product is a chopper module consisting of SiC-UMOSFET and SiC-SBD from ROHM.

## •Dimensions & Pin layout (Unit : mm)



#### •Absolute maximum ratings $(T_i = 25^{\circ}C)$

	、 J	,				
Parameter	Symbol	Conditions	Limit	Unit		
Drain-source voltage	$V_{DSS}$	G-S short	1200			
Repetitive reverse voltage	$V_{DSS}$	Clamp diode	1200			
Gate-source voltage(+)	V <sub>GSS</sub>		22	V		
Gate-source voltage(-)		D-S short	_4			
G - S Voltage (t <sub>surge</sub> <300nsec)	<sub>irge</sub> <300nsec) V <sub>GSSsurge</sub>		-4 to 26			
Drain current *1	I <sub>D</sub>	DC (T <sub>c</sub> =60°C)	180			
Drain current	I <sub>DRM</sub>	Pulse (T <sub>c</sub> =60°C) 1ms * <sup>2</sup>	360			
Source current * <sup>1</sup>	ا <sub>S</sub>	DC (T <sub>c</sub> =60°C ) V <sub>GS</sub> =18V	180			
	I <sub>SRM</sub>	Pulse (Tc=60°C) 1ms V <sub>GS</sub> =18V * <sup>2</sup>	360	Α		
	I <sub>SRM</sub>	Pulse (Tc=60°C) 10 $\mu$ s V <sub>GS</sub> =0V * <sup>2</sup>	360			
Forward curent	١ <sub>F</sub>	DC (T <sub>c</sub> =60°C ) V <sub>GS</sub> =18V	180			
(clamp diode) * <sup>1</sup>		Pulse (Tc=60°C) 1ms $V_{GS}$ =18V * <sup>2</sup>	360			
Total power disspation *3	Ptot	T <sub>c</sub> =25°C	880	W		
Max Junction Temperature	T <sub>jmax</sub>		175			
Junction temperature	T <sub>jop</sub>		-40 to150	°C		
Storage temperature	T <sub>stg</sub>		-40 to125			
Isolation voltage	Visol	Terminals to baseplate, f=60Hz AC 1min.250		Vrms		
Mounting torque		Main Terminals : M6 screw	4.5	NI me		
Mounting torque	_	Mounting to heat shink : M5 screw	3.5	N · m		

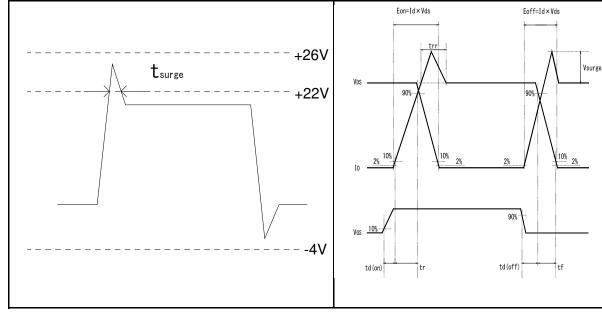
(\*1) Case temperature  $(T_c)$  is defined on the surface of base plate just under the chips.

(\*2) Repetition rate should be kept within the range where temperature rise if die should not exceed  $T_{j max}$ .

(\*3)  $T_i$  is less than 175°C

## •Example of acceptable VGS waveform

#### •Waveform for switching test



#### •Electrical characteristics (T<sub>i</sub>=25°C)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Static drain-source on-state voltage	V <sub>DS(on)</sub>	I <sub>C</sub> =180A, V <sub>GS</sub> =18V	T <sub>j</sub> =25°C	-	1.8	2.6	V
			T <sub>j</sub> =125°C	-	2.7	-	
			T <sub>j</sub> =150°C	-	3.1	4.0	
Drain cutoff current	I <sub>DSS</sub>	V <sub>DS</sub> =1200V, V <sub>GS</sub> =0V		-	-	10	μA
Forwad Voltag	V <sub>F</sub>	I <sub>F</sub> =180A	T <sub>j</sub> =25°C	-	1.6	2.2	v
			T <sub>j</sub> =125°C		2.0	-	
			T <sub>j</sub> =150°C	-	2.2	3.3	
Reverse curent	I <sub>RRM</sub>	Clamp diode		-	-	3.2	mA
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS}$ =10V, $I_{D}$ =50mA	$V_{DS}$ =10V, I <sub>D</sub> =50mA		-	5.6	V
Gate-source leakage current		V <sub>GS</sub> =22V, V <sub>DS</sub> =0V		-	-	0.5	^
	I <sub>GSS</sub>	$V_{GS}$ = -4V, $V_{DS}$ =0V		-0.5	-	-	μΑ
Switching characteristics	t <sub>d(on)</sub>	V <sub>GS(on)</sub> =18V, V <sub>GS(off)</sub> =0V		-	30	-	ns
	t <sub>r</sub>	$V_{DS}=600V$ $I_{D}=180A$ $R_{G}=3.9\Omega$ inductive load		-	45	-	
	t <sub>rr</sub>			-	20	-	
	t <sub>d(off)</sub>			-	165	-	
	t <sub>f</sub>			-	45	-	
Input capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,100kHz		-	9	-	nF
Gate Registance	R <sub>Gint</sub>	T <sub>j</sub> =25°C		-	1.4	-	Ω
Stray Inductance	Ls				25	-	nH
Creepage Distance	-	Terminal to heat sink			12.5	-	mm
		Terminal to terminal			20	-	mm
Clearance Distance	-	Terminal to heat sink			10.5	-	mm
		Terminal to terminal			14.0	-	mm
Junction-to-case thermal		UMOS (1/2 module) * <sup>4</sup>		-	-	0.17	
resistance	R <sub>th</sub> (j-c)	SBD (1/2 module) * <sup>4</sup>		-	-	0.14	°C/W
Case-to-heat sink Thermal resistance	R <sub>th</sub> (c-f)	Case to heat sink, per 1 module, Thermal grease applied * <sup>5</sup>		-	0.035	-	

(\*4) Measurement of Tc is to be done at the point just under the chip.

(\*5) Typical value is measured by using thermally conductive grease of  $\lambda$ =0.9W/(m · K).

(\*6) SiC devices have lower short cuicuit withstand capability due to high current density. Please be advised to pay careful attention to short cuicuit accident and try to adjust protection time to shutdown them as short as possible.

(\*7) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be dameged, please replace such Product with a new one.

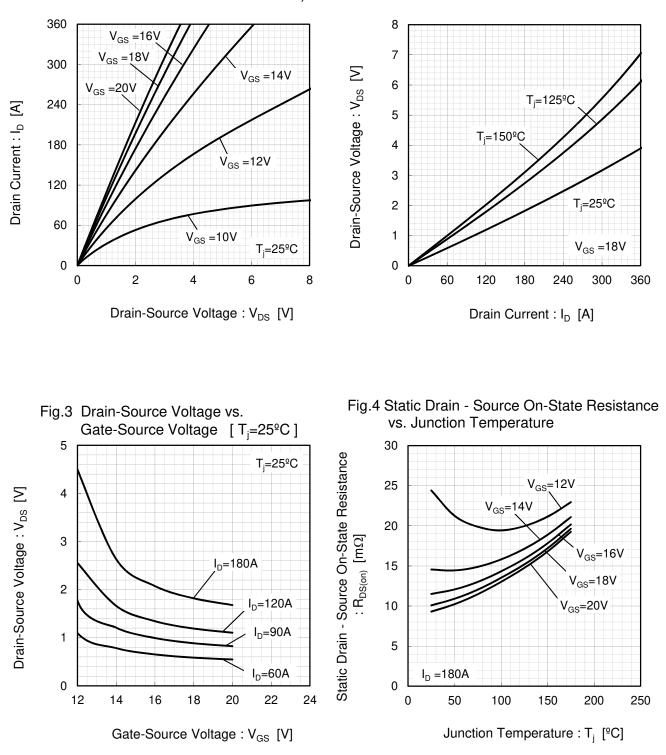


Fig.1 Typical Output Characteristics [T<sub>j</sub>=25°C] Fig.2 Drain-Source Voltage vs. Drain Current

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### •Electrical characteristic curves (Typical)

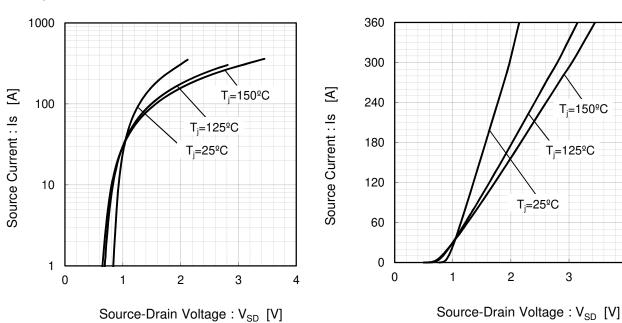
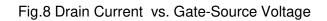
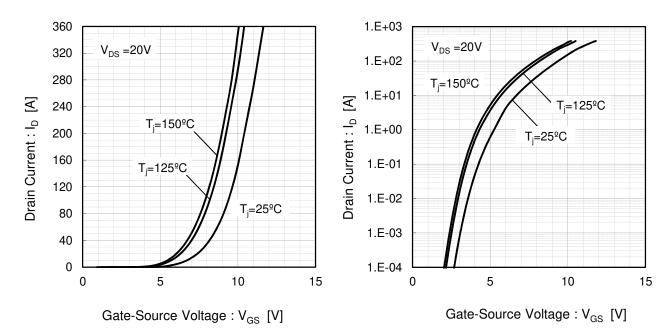


Fig.5 Forward characteristic of Diode

Fig.6 Forward characteristic of Diode

#### Fig.7 Drain Current vs. Gate-Source Voltage





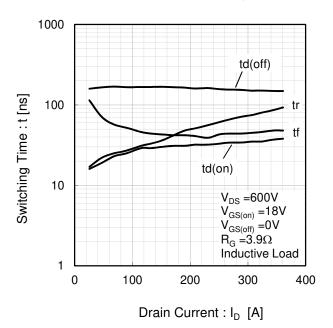


Fig.9 Switching Characteristics [ $T_j=25^{\circ}C$ ]

Fig.10 Switching Characteristics [ $T_j=125^{\circ}C$ ]

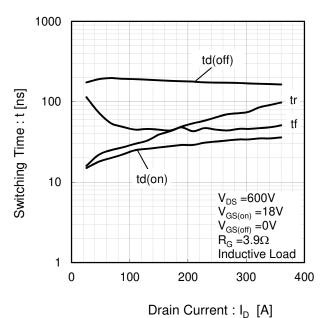
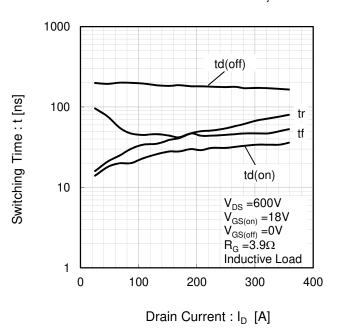
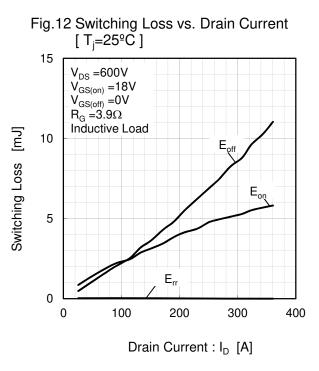
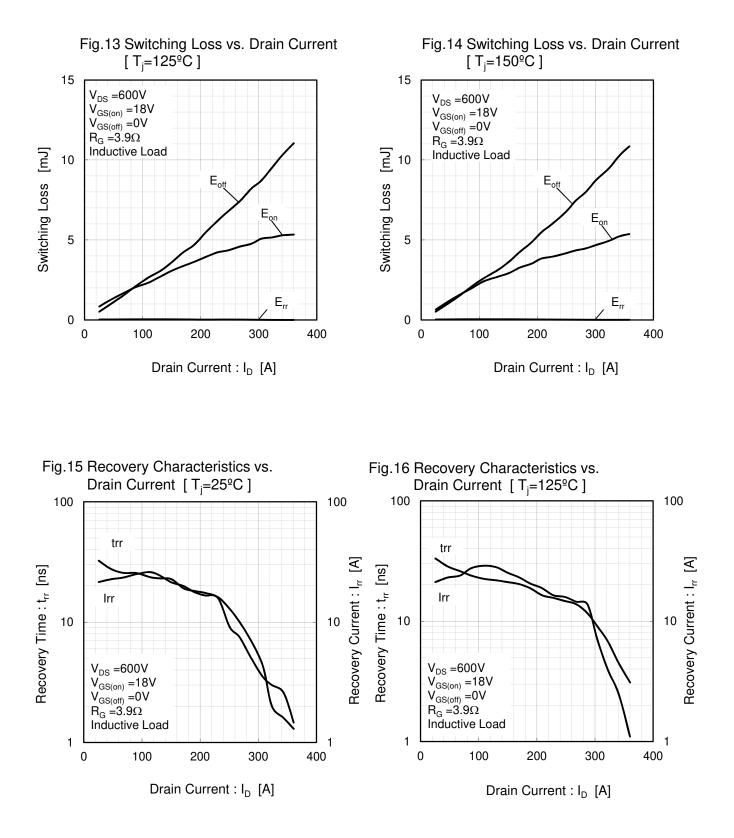
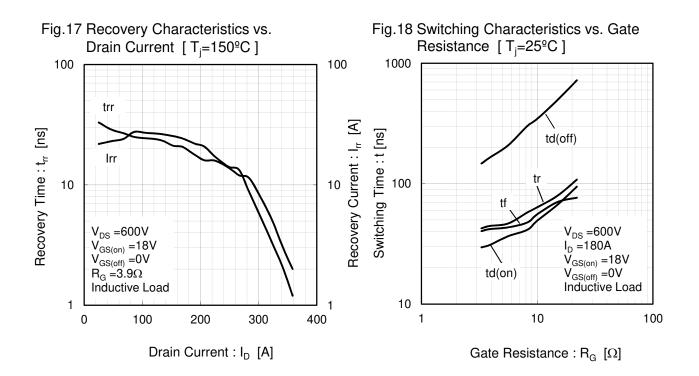


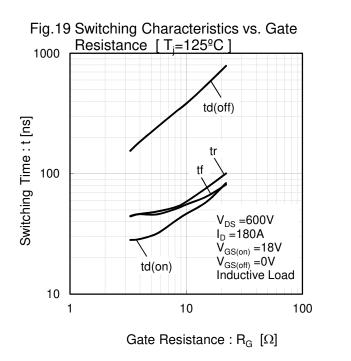
Fig.11 Switching Characteristics [T<sub>i</sub>=150°C]

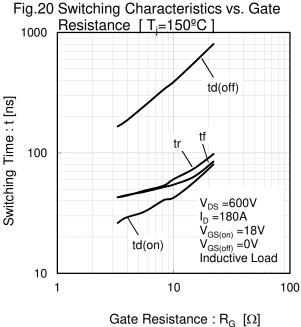


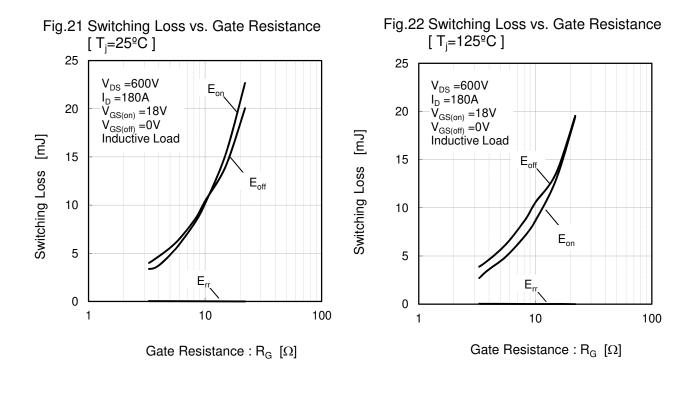












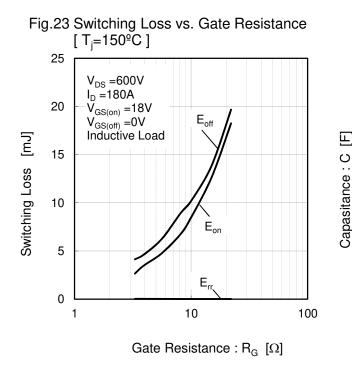
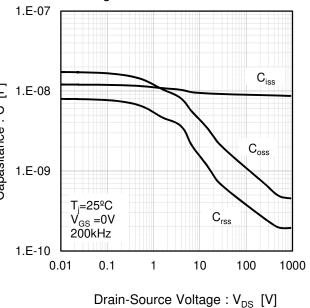
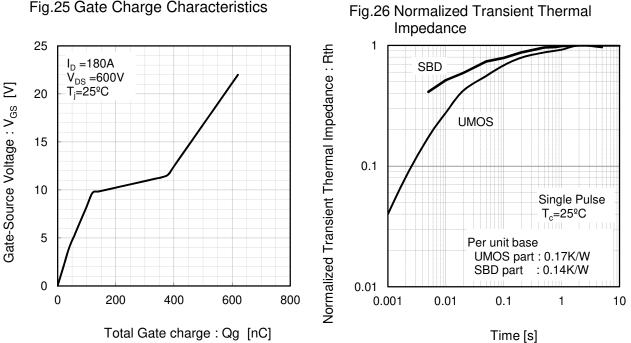


Fig.24 Typical Capacitance vs. Drain-Source Voltage





# Fig.25 Gate Charge Characteristics

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